

isc P-Channel MOSFET Transistor

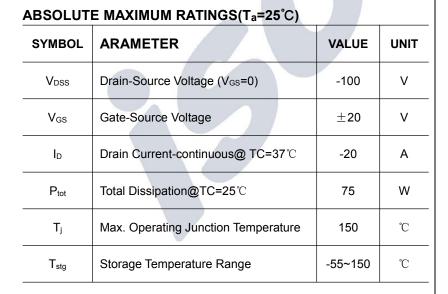
2SJ221

DESCRIPTION

- Low On Resistance
- High Speed Switching
- Low Drive Current
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

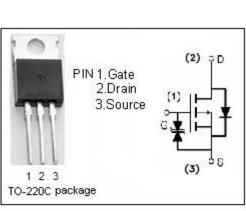
APPLICATIONS

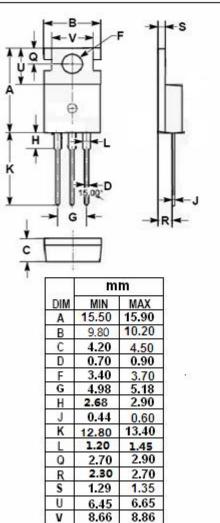
High speed switching application



THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	МАХ	UNIT
R _{th j-c}	Thermal Resistance, Junction to Case 3.1		°C/W
R _{th j-a}	Thermal Resistance, Junction to Ambient	75	°C/W







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	ELECTRICAL CHARACTERISTICS (TC=25 C)								
SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	UNIT				
V _{(BR)DSS}	Drain-Source Breakdown Voltage	V _{GS} = 0; I _D = -10mA	-100		V				
$V_{\text{GS(TH)}}$	Gate Threshold Voltage	V _{DS} = V _{GS} ; I _D = -1mA	-1.0	-2	V				
R _{DS(ON)}	Drain-Source On-stage Resistance	V _{GS} = -10V; I _D = -10A		0.16	Ω				
I _{GSS}	Gate Source Leakage Current	V _{GS} = -16V;V _{DS} = 0		-10	uA				
IDSS	Zero Gate Voltage Drain Current	V _{DS} = -80V,V _{GS} = 0		-0.25	mA				
V_{SD}	Diode Forward Voltage	I _F =-20 A;V _{GS} = 0		-1.05	V				

• ELECTRICAL CHARACTERISTICS (Tc=25°C)

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